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Kind regards,

Team Nexperia



Product data sheet

# **Product profile**

# 1.1 General description

PNP transistor in a SOT323 (SC-70) plastic package. The NPN complement is 2PC4081.

### 1.2 Features

- Low current (max. 150 mA)
- Low voltage (max. 50 V)
- Low collector capacitance (typ. 2.5 pF)

### 1.3 Applications

■ General-purpose switching and amplification

### 2. **Pinning information**

Table 1. **Pinning** 

Pin	Description	Simplified outline	Symbol
1	base		_
2	emitter		3 
3	collector	1 2	1 —
			sym013

### **Ordering information** 3.

**Ordering information** Table 2.

Type number	Package				
	Name	Description	Version		
2PA1576Q	SC-70	plastic surface mounted package; 3 leads	SOT323		
2PA1576R					
2PA1576S	_				



### **PNP** general-purpose transistor

# 4. Marking

Table 3. Marking codes

Type number	Marking code <sup>[1]</sup>
2PA1576Q	F*Q
2PA1576R	F*R
2PA1576S	F*S

<sup>[1] \* = -:</sup> made in Hong Kong

# 5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

		• • •	,		
Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter	-	-60	V
$V_{\text{CEO}}$	collector-emitter voltage	open base	-	<b>-50</b>	V
$V_{EBO}$	emitter-base voltage	open collector	-	-6	V
I <sub>C</sub>	collector current (DC)		-	-150	mA
I <sub>CM</sub>	peak collector current		-	-200	mA
I <sub>BM</sub>	peak base current		-	-200	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$	<u>[1]</u> _	200	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
T <sub>j</sub>	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C

<sup>[1]</sup> Transistor mounted on an FR4 printed-circuit board, single-sided copper, tin-plated and standard footprint.

# 6. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient		<u>[1]</u> -	-	625	K/W

<sup>[1]</sup> Transistor mounted on an FR4 printed-circuit board, single-sided copper, tin-plated and standard footprint.

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<sup>\* =</sup> t: made in Malaysia

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# **Characteristics**

**Product data sheet** 

Table 6. Characteristics

 $T_{amb} = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off current	$I_E = 0 A; V_{CB} = -30 V$	-	-	-100	nA
		$I_E = 0 \text{ A}; V_{CB} = -30 \text{ V};$ $T_j = 150 \text{ °C}$	-	-	<b>-5</b>	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	$I_C = 0 A; V_{EB} = -4 V$	-	-	-100	nA
h <sub>FE</sub>	DC current gain	$I_C = -1 \text{ mA}; V_{CE} = -6 \text{ V}$				
	2PA1576Q		120	-	270	
	2PA1576R		180	-	390	
	2PA1576S		270	-	560	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = -50 \text{ mA};$ $I_B = -5 \text{ mA}$	[1] -	-	-500	mV
C <sub>c</sub>	collector capacitance	$I_E = i_e = 0 \text{ A};$ $V_{CB} = -12 \text{ V}; f = 1 \text{ MHz}$	-	2.5	3.5	pF
f <sub>T</sub>	transition frequency	$I_C = -2 \text{ mA};$ $V_{CE} = -12 \text{ V};$ f = 100  MHz	100	-	-	MHz

<sup>[1]</sup> Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 

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### **Package outline** 8.

### Plastic surface-mounted package; 3 leads **SOT323** В Α X $H_{\mathsf{E}}$ = v (M) A Q **→** | w (M) B е detail X 2 mm scale **DIMENSIONS** (mm are the original dimensions) UNIT D С Ε Q bp e<sub>1</sub> ΗE $L_{\mathbf{p}}$ w max 0.25 2.2 1.35 0.23 0.1 1.3 0.65 0.2 0.2 mm 0.8 1.15 REFERENCES **EUROPEAN** OUTLINE **ISSUE DATE** PROJECTION VERSION IEC **JEDEC JEITA** 04-11-04 SOT323 SC-70

Package outline SOT323 (SC-70) Fig 1.

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06-03-16

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# 9. Revision history

# Table 7. Revision history

	•			
Document ID	Release date	Data sheet status	Change notice	Supersedes
2PA1576_6	20091117	Product data sheet	-	2PA1576_5
Modifications:		eet was changed to reflect t w legal definitions and discl		
	<ul><li>Figure 1 "Pa</li></ul>	ckage outline SOT323 (SC-	70)": updated	
2PA1576_5	20041124	Product data sheet	-	2PA1576_4
2PA1576_4	19990531	Product specification	-	2PA1576_3
2PA1576_3	19970328	Objective specification	-	2PA1576_2
2PA1576_2	19931213	n.a.	-	n.a.

# PNP general-purpose transistor

# 10. Legal information

### 10.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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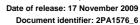
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